

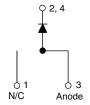
RoHS

HALOGEN

**FREE** 

# HEXFRED®, Ultrafast Soft Recovery Diode, 4 A





DPAK (	TO-252AA)	۱
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PRIMARY CHARACTERISTICS				
I <sub>F(AV)</sub>	4 A			
$V_{R}$	600 V			
V <sub>F</sub> at I <sub>F</sub>	1.4 V			
t <sub>rr</sub> typ.	17 ns			
T <sub>J</sub> max.	150 °C			
Package	DPAK (TO-252AA)			
Circuit configuration	Single			

#### **FEATURES**

- · Ultrafast recovery time
- Ultrasoft recovery
- Very low I<sub>RRM</sub>
- Very low Q<sub>rr</sub>
- · Guaranteed avalanche
- Specified at operating temperature
- AEC-Q101 qualified
- Meets JESD 201 class 2 whisker test
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- Material categorization: for definitions of compliance please see <a href="https://www.vishav.com/doc?99912">www.vishav.com/doc?99912</a>

#### **BENEFITS**

- Reduced RFI and EMI
- Reduced power loss in diode and switching transistor
- Higher frequency operation
- · Reduced snubbing
- · Reduced parts count

## **DESCRIPTION / APPLICATIONS**

These diodes are optimized to reduce losses and EMI / RFI in high frequency power conditioning systems. The softness of the recovery eliminates the need for a snubber in most applications. These devices are ideally suited for freewheeling, flyback, power converters, motor drives, and other applications where high speed and reduced switching losses are design requirements.

ABSOLUTE MAXIMUM RATINGS					
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS	
Cathode to anode voltage	$V_{RRM}$		600	V	
Maximum continuous forward current	I <sub>F(AV)</sub>	T <sub>C</sub> = 100 °C	4		
Single pulse forward current	I <sub>FSM</sub>		25	Α	
Repetitive peak forward current	I <sub>FRM</sub>	T <sub>C</sub> = 116 °C	16		
Maximum power dissipation	$P_{D}$	T <sub>C</sub> = 100 °C	10	W	
Operating junction and storage temperatures	T <sub>J</sub> , T <sub>Stg</sub>		-55 to +150	°C	

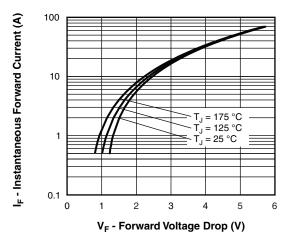


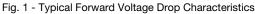


<b>ELECTRICAL SPECIFICATIONS</b> (T <sub>J</sub> = 25 °C unless otherwise specified)						
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS
Breakdown voltage, blocking voltage	$V_{BR}, \ V_{R}$	I <sub>R</sub> = 100 μA	600	-	-	
Forward voltage See fig. 1		I <sub>F</sub> = 4 A	-	1.5	1.8	V
	$V_{F}$	I <sub>F</sub> = 8 A	-	1.8	2.2	
ooo ng. 1		I <sub>F</sub> = 4 A, T <sub>J</sub> = 125 °C	-	1.4	1.7	
Maximum reverse		$V_R = V_R$ rated	-	0.17	3.0	μA
leakage current	I <sub>R</sub>	$T_J = 125  ^{\circ}\text{C},  V_R = 0.8  \text{x}  V_R  \text{rated}$	-	44	300	μΑ
Junction capacitance	C <sub>T</sub>	V <sub>R</sub> = 200 V	-	4	8	рF
Series inductance	L <sub>S</sub>	Measured lead to lead 5 mm from package body	-	8.0	-	nΗ

<b>DYNAMIC RECOVERY CHARACTERISTICS</b> (T <sub>C</sub> = 25 °C unless otherwise specified)							
PARAMETER	SYMBOL	TEST CO	NDITIONS	MIN.	TYP.	MAX.	UNITS
		$I_F = 1.0 \text{ A}, dI_F/dt = 200 \text{ A}$	$A/\mu A$ , $V_R = 30 \text{ V}$	-	17	-	
Reverse recovery time	t <sub>rr</sub>	T <sub>J</sub> = 25 °C	I <sub>F</sub> = 4 A	-	28	42	ns
		T <sub>J</sub> = 125 °C		-	38	57	
Peak recovery current I <sub>RRM</sub>		T <sub>J</sub> = 25 °C		-	2.9	5.2	Α
	IRRM	T <sub>J</sub> = 125 °C		-	3.7	6.7	
Poverse recovery charge	0	T <sub>J</sub> = 25 °C	dl <sub>F</sub> /dt = 200 A/μs V <sub>B</sub> = 200 V	-	40	60	nC
Reverse recovery charge Q <sub>rr</sub>	Qrr	T <sub>J</sub> = 125 °C		-	70	105	IIC
Date of fall of vocasions assured	of fall of recovery current dI <sub>(rec)M</sub> /dt	T <sub>J</sub> = 25 °C		-	280	-	A/µs
hate of fall of recovery current		T <sub>J</sub> = 125 °C		-	235	-	ΑνμS

THERMAL - MECHANICAL SPECIFICATIONS						
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS
Maximum junction and storage temperature range	T <sub>J</sub> , T <sub>Stg</sub>		-55	-	150	°C
Thermal resistance, junction to case	R <sub>thJC</sub>		-	-	5.0	°C/W
Thermal resistance, junction to ambient	R <sub>thJA</sub>	Typical socket mount	-	-	80	C/VV
Weight			-	2.0	-	g
vveignit			-	0.07	-	oz.
Mounting torque			6.0 (5.0)	-	12 (10)	kgf · cm (lbf · in)
Marking device		Case style DPAK (TO-252AA)		HFA04S	SD60SH	•





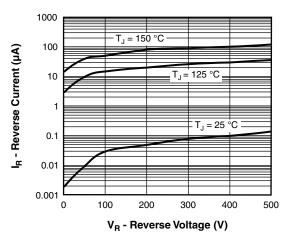


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

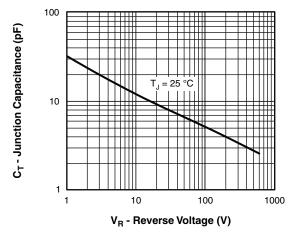


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

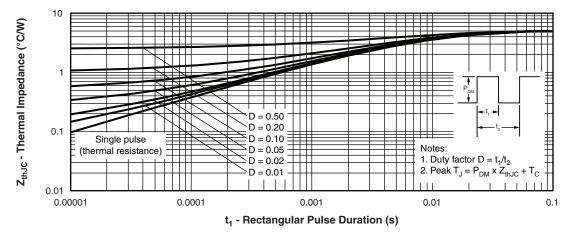


Fig. 4 - Maximum Thermal Impedance Z<sub>thJC</sub> Characteristics



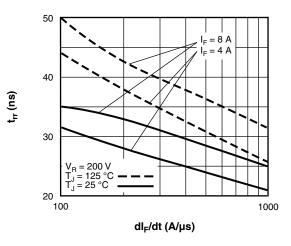


Fig. 5 - Typical Reverse Recovery Time vs. dl<sub>F</sub>/dt

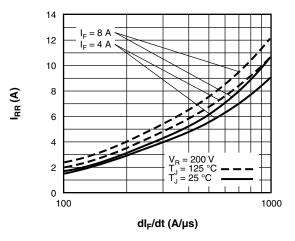


Fig. 6 - Typical Recovery Current vs. dl<sub>F</sub>/dt

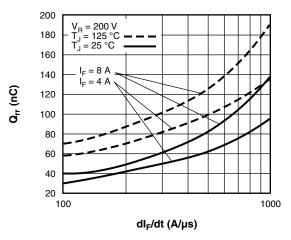


Fig. 7 - Typical Stored Charge vs.  $dI_F/dt$ 

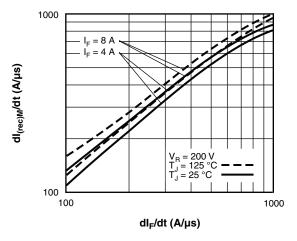


Fig. 8 - Typical  $dI_{(rec)M}/dt$  vs.  $dI_F/dt$ 

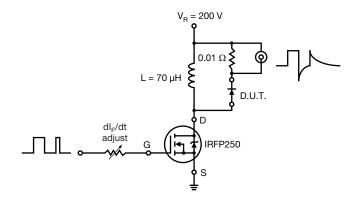
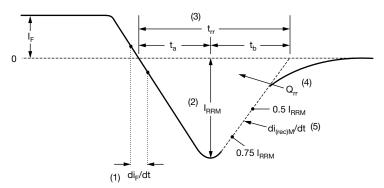


Fig. 9 - Reverse Recovery Parameter Test Circuit



- (1) di<sub>F</sub>/dt rate of change of current through zero crossing
- (2)  $I_{RRM}$  peak reverse recovery current
- (3)  $\rm t_{rr}$  reverse recovery time measured from zero crossing point of negative going  $\rm I_F$  to point where a line passing through 0.75  $\rm I_{RRM}$  and 0.50  $\rm I_{RRM}$  extrapolated to zero current.
- (4)  $\mathbf{Q}_{\rm rr}$  area under curve defined by  $\mathbf{t}_{\rm rr}$  and  $\mathbf{I}_{\rm RRM}$

$$Q_{rr} = \frac{t_{rr} \times I_{RRM}}{2}$$

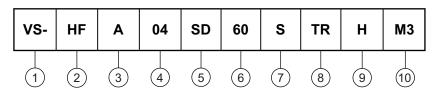
(5)  $di_{(rec)M}/dt$  - peak rate of change of current during  $t_b$  portion of  $t_{rr}$ 

Fig. 10 - Reverse Recovery Waveform and Definitions



## **ORDERING INFORMATION TABLE**

Device code



1 - Vishay Semiconductors product

- HEXFRED® family

3 - Electron irradiated

Current rating (04 = 4 A)

5 - D-PAK

6 - Voltage rating (60 = 600 V)

7 - S = D-PAK

8 - • TR = tape and reel

• R = tape and reel (right oriented)

• L = tape and reel (left oriented)

9 - H = AEC-Q101 qualified

10 - Environmental digit:

M3 = halogen-free, RoHS-compliant, and terminations lead (Pb)-free

ORDERING INFORMATION (Example)					
PREFERRED P/N	BASE QUANTITY	PACKAGING DESCRIPTION			
VS-HFA04SD60SHM3	75	Antistatic plastic tube			
VS-HFA04SD60STRHM3	2000	13" diameter reel			
VS-HFA04SD60STRRHM3	3000	13" diameter reel			
VS-HFA04SD60STRLHM3	3000	13" diameter reel			

LINKS TO RELATED DOCUMENTS		
Dimensions <u>www.vishay.com/doc?95519</u>		
Part marking information	www.vishay.com/doc?95518	
Packaging information	www.vishay.com/doc?95033	



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